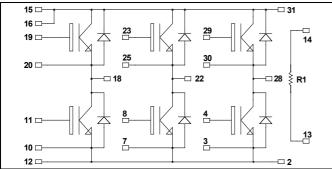
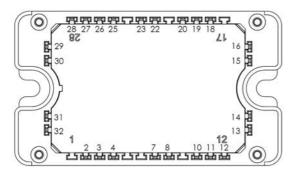


3 Phase bridge Trench + Field Stop IGBT3 Power Module



It is recommended to connect a decoupling capacitor between pins 31 & 2 to reduce switching overvoltages, if DC Power is connected between pins 15, 16 & 12. Pins 15 & 16 must be shorted together.



APTGT25X120T3G

$\mathbf{V}_{\text{CES}} = \mathbf{1200V}$

 $I_C = 25A$ @ $T_c = 80^{\circ}C$

Application

Motor control

Features

• Trench + Field Stop IGBT3

- Low voltage drop
- Low tail current
- Switching frequency up to 20 kHz
- Low leakage current
- RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter		Max ratings	Unit
V _{CES}	Collector - Emitter Voltage		1200	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	40	
IC		$T_C = 80^{\circ}C$	25	А
I _{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	50	
V _{GE}	Gate – Emitter Voltage		±20	V
P_D	Power Dissipation	$T_C = 25^{\circ}C$	156	W
RBSOA	Reverse Bias Safe Operation Area	$T_j = 125^{\circ}C$	50A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



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Electrical Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.7	2.1	V
V _{CE(sat)}		$I_C = 25A$	$T_j = 125^{\circ}C$		2.0		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1mA$		5.0	5.8	6.5	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$			1800		лF
Cres	Reverse Transfer Capacitance	f = 1 MHz			82		pF
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_C = 25A$			90		
Tr	Rise Time				30		ns
$T_{d(off)}$	Turn-off Delay Time				420		
T_{f}	Fall Time	$R_G = 27\Omega$		70			
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C)			90		
Tr	Rise Time	$V_{GE} = \pm 15V$			50		ns
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 600V$ $I_C = 25A$			520		
T_{f}	Fall Time	$\frac{I_{\rm C} - 23R}{R_{\rm G} = 27\Omega}$			90		
Eon	Turn-on Switching Energy	$\begin{array}{l} V_{GE}=\pm 15V\\ V_{Bus}=600V \end{array}$	$T_j = 125^{\circ}C$		2.5		- m I
E_{off}	Turn-off Switching Energy	$I_{\rm C} = 25 A$ $R_{\rm G} = 27 \Omega$	$T_{j} = 125^{\circ}\mathrm{C}$		2.9		mJ
R_{thJC}	Junction to Case Thermal Resistance					0.8	°C/W

Reverse diode ratings and characteristics (Per diode)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Peak Repetitive Reverse Voltage					1200	V
I _{RM}	Reverse Leakage Current	V _R =1200V				100	μA
I_F	DC Forward Current		$Tc = 80^{\circ}C$		30		А
	Diode Forward Voltage	$I_F = 30A$			2.6	3.1	
$V_{\rm F}$		$I_F = 60A$	$I_F = 60A$		3.2		V
		$I_F = 30A$	$T_{j} = 125^{\circ}C$		1.8		
	Reverse Recovery Time	$I_F = 30A$	$T_j = 25^{\circ}C$		300		
t _{rr}			$T_j = 125^{\circ}C$		380		ns
Q _{rr}	Reverse Recovery Charge	$V_R = 800V$ di/dt = 200A/µs	$T_j = 25^{\circ}C$	36	360		тC
			$T_j = 125^{\circ}C$		1700		nC
R_{thJC}	Junction to Case Thermal Resistance					1.2	°C/W

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Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

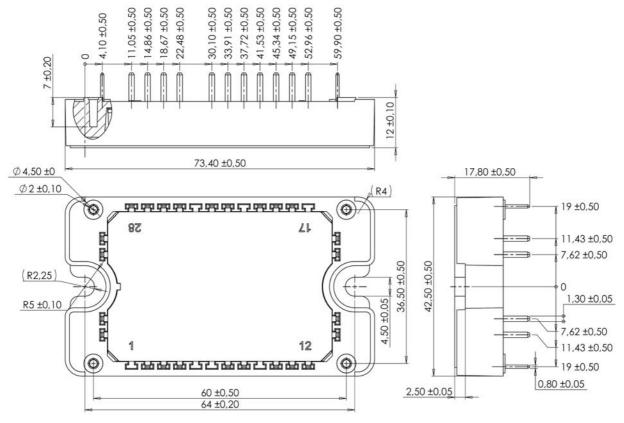
Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B _{25/85}	$T_{25} = 298.15 \text{ K}$			3952		Κ
$\Delta B/B$		T _C =100°C		4		%
	D					

 $\overline{R_{T}} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$ T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
TJ	Operating junction temperature range			-40	150	
T _{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T _{STG}	Storage Temperature Range			-40	125	C
T _C	Operating Case Temperature				125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

Package outline (dimensions in mm)



See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

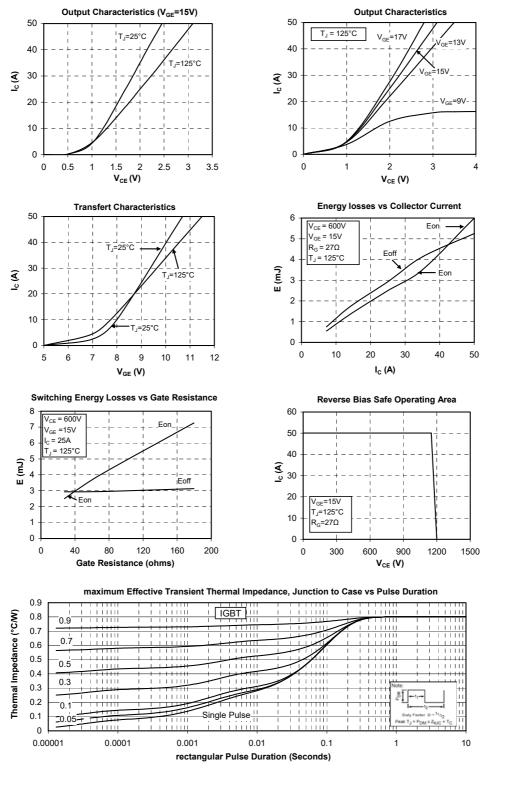
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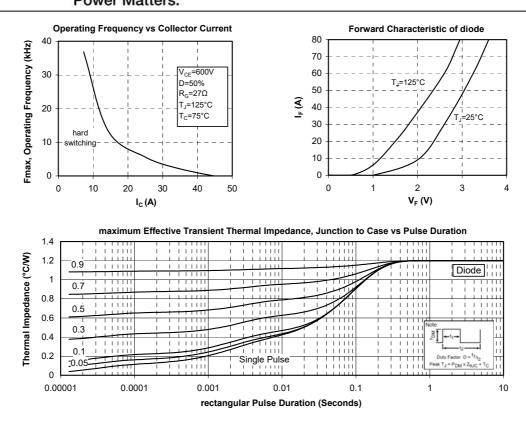
Typical Performance Curve



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